## REVERSE VOLTAGE - 50 to 60 Volts FORWARD CURRENT - 3.0 Amperes

## DO-201AD

| DO-201AD |  |  |
| :---: | :---: | :---: |
| Dim. | Min. | Max. |
| A | 25.4 | - |
| B | 7.30 | 9.50 |
| C | 1.20 | 1.30 |
| D | 4.80 | 5.30 |
| All Dimensions in millimeter |  |  |



## MECHANICAL DATA

- Case: JEDEC DO-201AD molded plastic
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- Polarity: Color band denotes cathode
- Weight:0.04 ounces, 1.1 grams
- Mounting position: Any
- IEC 61000-4-2, level 4 (ESD), > 15KV (air)


## FEATURES

- Metal-Semiconductor junction with guard ring
- Epitaxial construction
- Low forward voltage drop
- High current capability
- The plastic material carries UL recognition 94V-0
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection application


MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS
Ratings at $25^{\circ} \mathrm{C}$ ambient temperature unless otherwise specified.

| CHARACTERISTICS | SYMBOL | SB350 | SB360 | UNIT |
| :---: | :---: | :---: | :---: | :---: |
| Maximum Repetitive Peak Reverse Voltage | $\mathrm{V}_{\text {RRM }}$ | 50 | 60 | V |
| Maximum RMS Voltage | $\mathrm{V}_{\text {RMS }}$ | 35 | 42 | V |
| Maximum DC Blocking Voltage | VDC | 50 | 60 | V |
| Maximum Average Forward Rectified Current @Tc=115 ${ }^{\circ} \mathrm{C}$ | $\mathrm{I}_{\mathrm{AV}}$ | 3.0 |  | A |
| Peak Forward Surge 8.3 ms single half sine-wave superimposed on rated load | IFSM | 80 |  | A |
| Maximum Forward Voltage at 3.0A DC | $\mathrm{V}_{\mathrm{F}}$ | 0.74 |  | V |
| Maximum DC Reverse Current @Tj=25 ${ }^{\circ} \mathrm{C}$ at Rated DC Blocking Voltage $@ T \mathrm{j}=100^{\circ} \mathrm{C}$ | $I_{R}$ | $\begin{gathered} 0.05 \\ 20 \end{gathered}$ |  | mA |
| Typical Thermal Resistance (Note 1) | $\begin{aligned} & R_{\ominus J \iota} \\ & R_{\ominus J C} \end{aligned}$ | $\begin{aligned} & 10 \\ & 19 \end{aligned}$ |  | 0/W |
| Typical Junction Capacitance (Note 2) | Cj | 250 |  | pF |
| Operating Junction Temperature Range | Tj | -55 to +150 |  | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range | TstG | -55 to +150 |  | ${ }^{\circ} \mathrm{C}$ |

Note : (1)Thermal Resistance Junction to Lead and Case.
(2)Measured at 1.0 MHz and applied reverse voltage of 4.0 V DC .

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FIG.1- FORWARD CURRENT DERATING CURVE


FIG.3- TYPICAL JUNCTION CAPACITANCE


FIG.5-TYPICAL REVERSE CHARACTERISTICS


FIG.2- MAXIMUM NON-REPETITIVE SURGE


FIG.4- TYPICAL FORW ARD CHARACTERISTICS


FIG.6- DC REVERSE VOLTAGE DERATING CURVE


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